TEMIC
Semiconductors

U813BS/U813BSE

1.1-GHz Prescaler for PLLs in TV, CATV and SAT TV Tuners

Technology: Bipolar

Features

- U813BS ECL output stage
- U813BSE emitter-follower output stage
- 3 scaling factors 64/128/256, programmable at Pin 5
- High input sensitivity
- Low output impedance
- Low power consumption
- Pin-compatible to the U6xxB-series except Pin 5
- Electrostatic protection according to MIL-STD. 883

Case

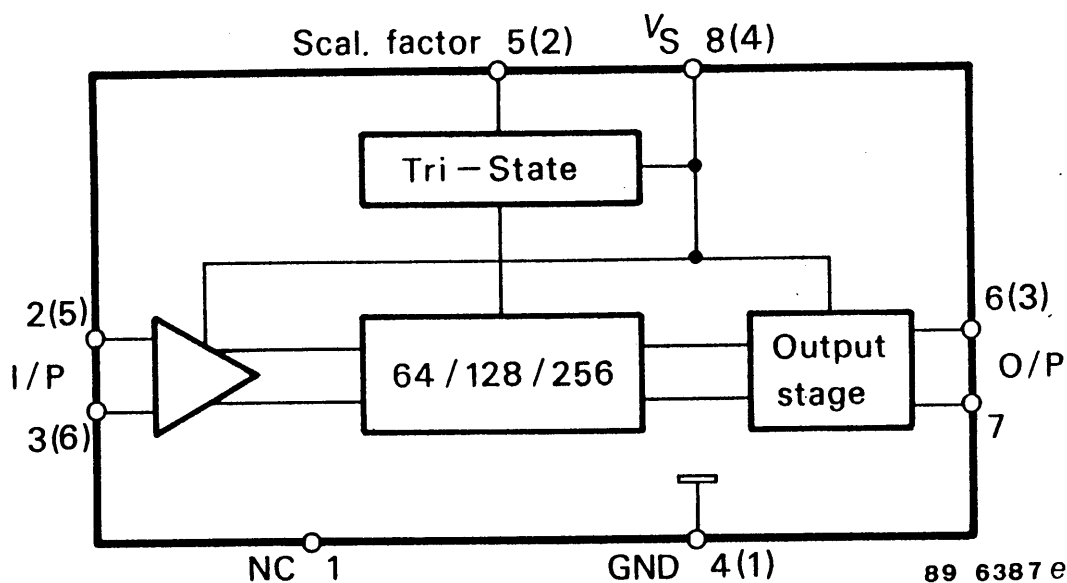|	
8-pin dual-inline plastic	(U813BS, U813BSE)
8-pin SO plastic	(U813BS-FP, U813BSE-FP)
6-pin SIP plastic	(U813BS-SP, U813BSE-SP)

Block Diagram

Figure 1. Block diagram

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Absolute Maximum Ratings

Reference point pin 4 (1)

Parameters		Symbol	Value	Unit
Supply voltage	Pin 8 (4)	V_S	6	V
Input-voltage range	Pin 2, 3, 5 (2, 5, 6)	V_i	0 to V_S	V
Junction temperature		T_i	125	°C
Storage-temperature range		T_{stg}	–40 to +125	°C
Ambient-temperature range		T_{amb}	–25 to +70	°C

Thermal Resistance

Parameters		Symbol	Value	Unit
Junction ambient	DIP8		100	
	SIP6	R_{thJA}	100	K/W
	SO8		175	

Note:

The device is self-oscillating without input signal

Pin Description (Dip8, SO8)

Pin	Function
1	Not connected
2, 3	Input
4	Ground
5	Switch 64/128/256
6, 7	Output
8	V_S

Pin Description (SIP6)

Pin	Function
1	Ground
2	Switch 64/128/256
3	Output
4	V_S
5,6	Input

Notes:

Pin numbers without brackets apply to DIP8 and SO8 package,
Pin numbers with brackets to SIP6

RMS voltage calculated from the available power measured

Electrical Characteristics

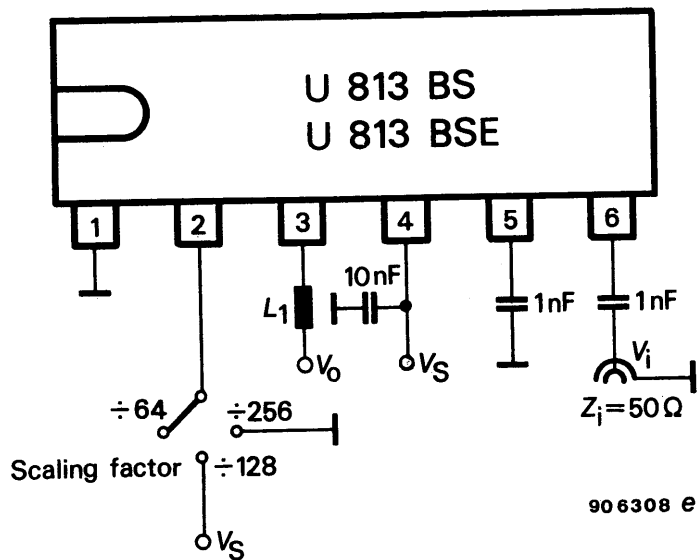V_S = 4.5 to 5.5 V, T_{amb} = 0 to +70°C, referred to test circuit, unless otherwise specified

Parameters	Test Conditions / Pin	Symbol	Min.	Typ.	Max.	Unit
Supply current	V_S = 5 V **U813BS** Pin 8 (4)	I_S		35	45	mA
	U813BSE Pin 8 (4)	I_S		38	50	mA
Input sensitivity	R_G = 50 Ω f_i = 70 to 1000 MHz Pin 2, 3 (5, 6)	V_i			10	mV
	f_i = 1000 to 1100 MHz Pin 2, 3 (5, 6)	V_i			15	mV
Large-signal compatibility	R_G = 50 Ω Pin 2, 3 (5, 6)	V_i	300			mV
Frequency range		f_{imin}			70	MHz
		f_{imax}	1100			
Output stage						
a. Balanced ECL output						
Voltage swing each output	R_L = 10 k//13 pF Pin 6, 7 (3)	V_O	0.8			V_{pp}
Output impedance	Pin 6, 7 (3)	Z_O		500		Ω
b. Emitter follower						
Voltage swing each output	R_L = 10 k//13 pF Pin 6, 7 (3)	V_O	1			V_{pp}
Output impedance	Pin 6, 7 (3)	Z_O		200		Ω
Switching voltage for	./. 64 Pin 5 (2)	V_{SF}		open		
	./. 128 Pin 5 (2)	V_{SF}	V_S –0.5			V
	./. 256 Pin 5 (2)	V_{SF}		0	0.5	V

Test Circuits
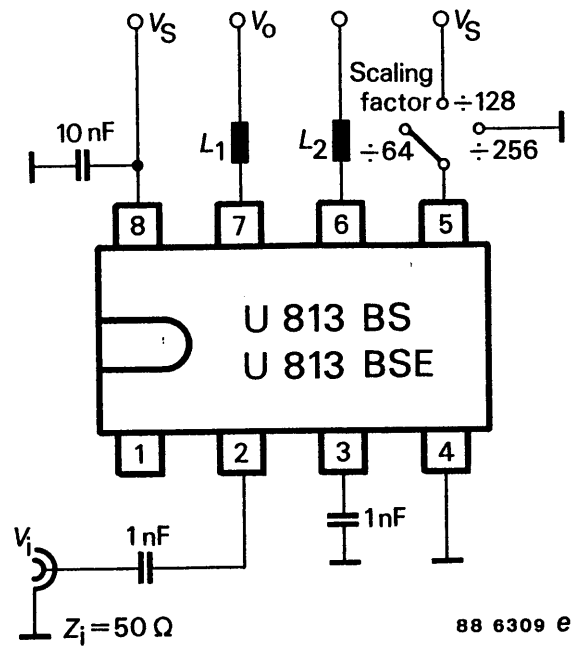
DIP 8/SO 8

Figure 2.

SIP 6

$L_1 = L_2 = 150$ nH (6 turns CuL 0.45 mm $\oslash$ on 4 mm $\oslash$)
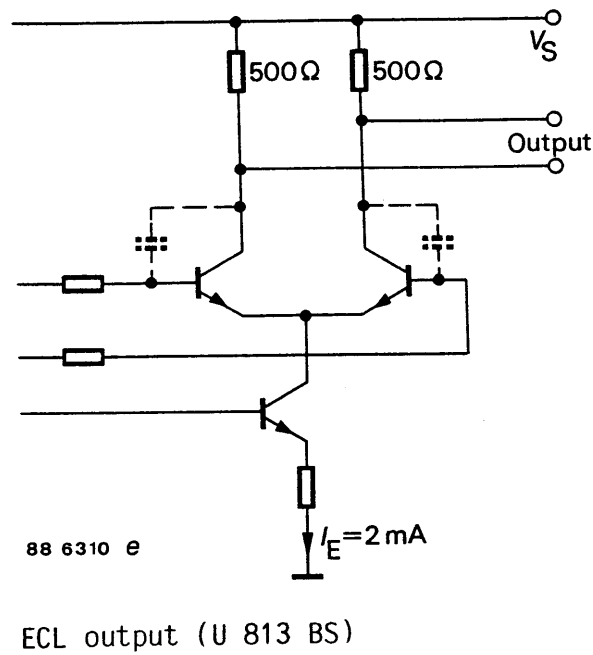
Figure 3.

Output Circuits

ECL output (U 813 BS)

Figure 4.

Emitter follower output (U 813 BSE)

Figure 5.

Dimensions in mm

technical drawings
according to DIN
specifications

8 614

Case
DIP 8-leads

technical drawings
according to DIN
specifications

6 688 e

Case
SO 8
(SOT 96 A)

technical drawings
according to DIN
specifications

4 653 e

Case
SIP 6
6-leads
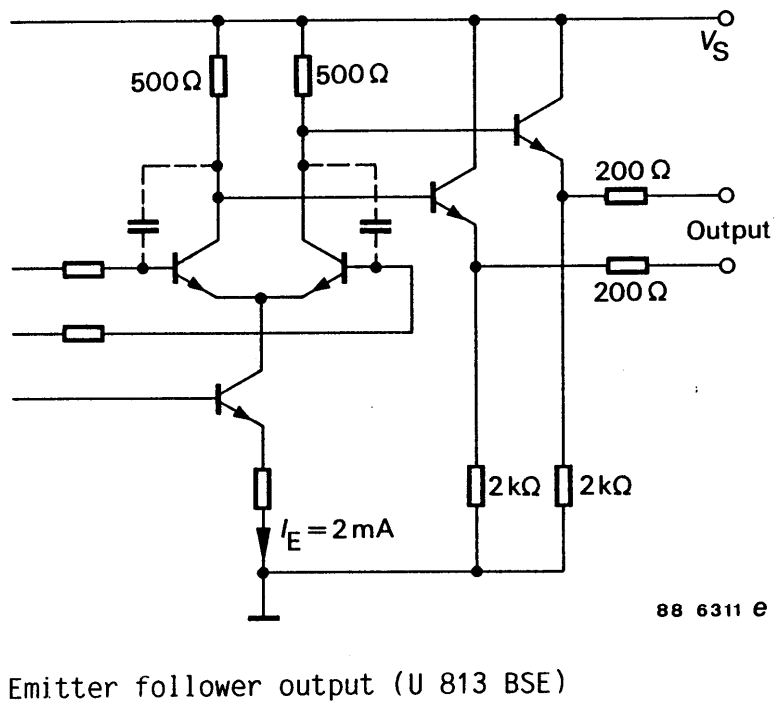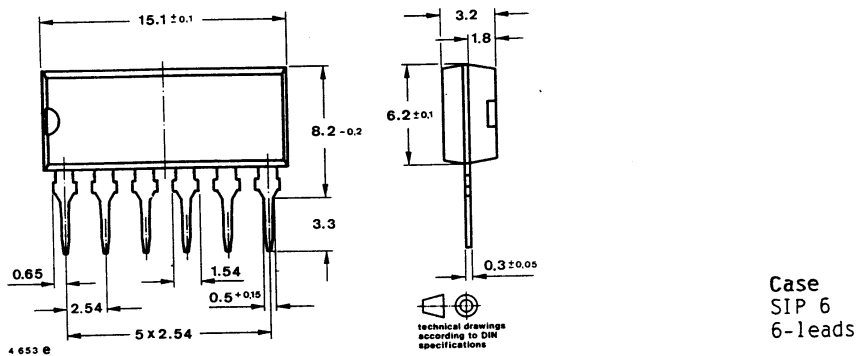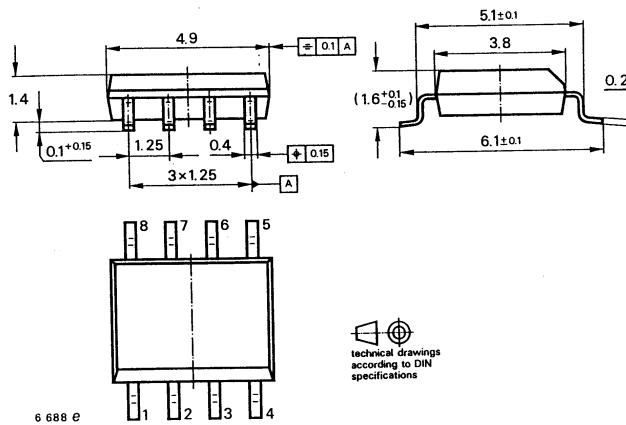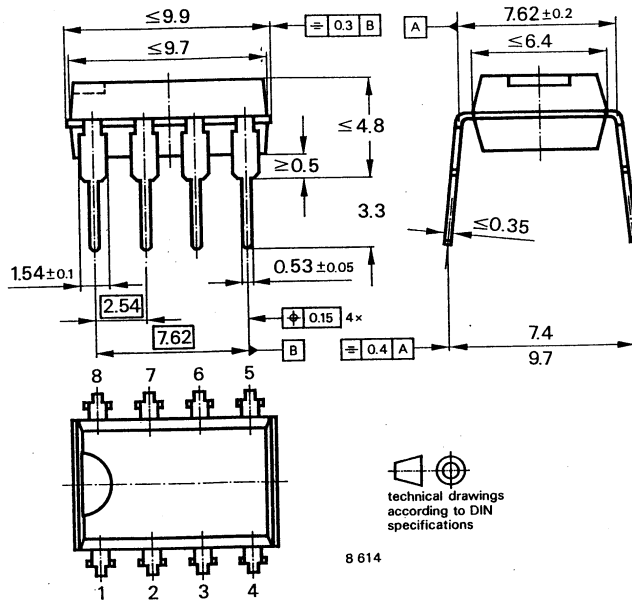
Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively

2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA

3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.